1N5620GP

SINTERED GLASS JUNCTION PLASTIC RECTIFIER

VOLTAGE: 800V CURRENT: 1.0A



FEATURE

High temperature metallurgically bonded construction Sintered glass cavity free junction Low reverse current Capability of meeting environmental standard of MIL-S-19500 High temperature soldering guaranteed 350°C /10sec/0.375"lead length at 5 lbs tension

MECHANICAL DATA

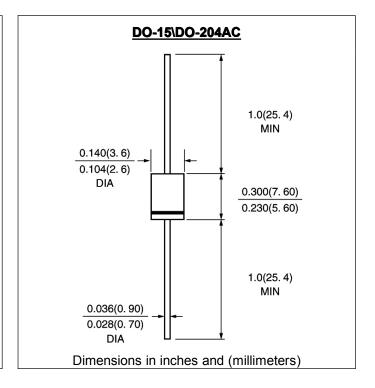
Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C

Case: Molded with UL-94 Class V-0 recognized Flame

Retardant Epoxy

Polarity: color band denotes cathode

Mounting position: any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

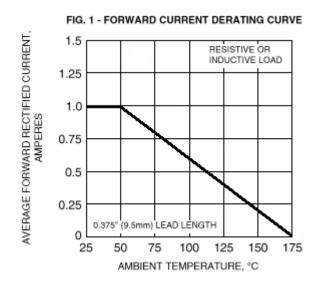
	SYMBOL	1N5620GP	units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	800	V
Maximum RMS Voltage	V _{RMS}	560	V
Maximum DC blocking Voltage	V _{DC}	800	V
Maximum Reverse Breakdown Voltage I _R =50μA	V_{BR}	880	V
Maximum Average Forward Rectified Current 3/8"lead length at Ta=50 $^{\circ}\mathrm{C}$	I _{FAV}	1.0	А
Peak Forward Surge Current 8.3ms single half sine- wave superimposed on rated load	I _{FSM}	50	А
Maximum Forward Voltage at Forward Current 3.0A and 25 $^{\circ}\mathrm{C}$	V _F	1.3	V
Maximum DC Reverse CurrentTa =25 °Cat rated DC blocking voltageTa =100 °C	l lo	1.0 25.0	μА
Maximum Reverse Recovery Time (Note 1)	Trr	2.0	μS
Typical Junction Capacitance (Note 2)	Cj	50.0	pF
Typical Thermal Resistance (Note 3)	Rth(ja)	35.0	°C /W
Storage and Operating Junction Temperature	Tstg, Tj	-65 to +175	°C

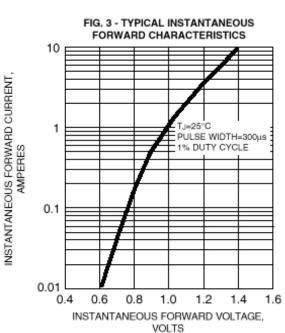
Note:

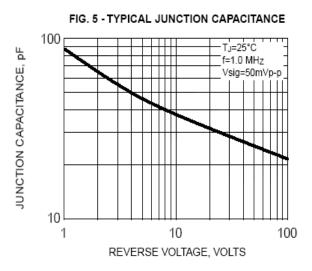
- 1. Reverse Recovery Condition If =0.5A, Ir =1.0A, Irr =0.25A
- 2. Measured at 1.0 MHz and applied reverse voltage of 12.0Vdc
- 3. Thermal Resistance from Junction to Ambient at 3/8"lead length, P.C. Board Mounted

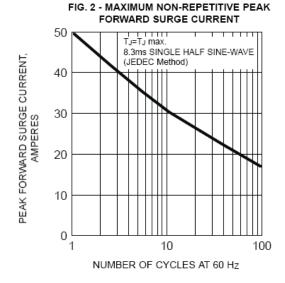
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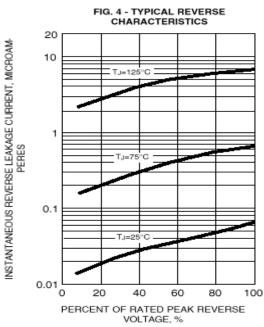
RATINGS AND CHARACTERISTIC CURVES 1N5620GP











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